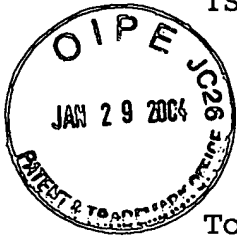


TSMC-02-1193



January 6, 2004

To: Commissioner for Patents  
P.O.Box 1450  
Alexandria, VA 22313-1450

Fr: George O. Saile, Reg. No. 19,572  
28 Davis Avenue  
Poughkeepsie, N.Y. 12603

Subject: | Serial No. 10/694,684 10/28/03 |  
Ping-Yi Hsin et al.  
METHOD OF FORMING METAL-INSULATOR-  
METAL (MIM) CAPACITORS AT COPPER  
PROCESS  
| \_\_\_\_\_ |

#### INFORMATION DISCLOSURE STATEMENT

Enclosed is Form PTO-1449, Information Disclosure Citation  
In An Application.

The following Patents and/or Publications are submitted to  
comply with the duty of disclosure under CFR 1.97-1.99 and  
37 CFR 1.56.

#### CERTIFICATE OF MAILING

I hereby certify that this correspondence is being  
deposited with the United States Postal Service as first class  
mail in an envelope addressed to: Commissioner for Patents,  
P.O. Box 1450, Alexandria, VA 22313-1450, on January 27, 2004.

Stephen B. Ackerman, Reg.# 37761

Signature/Date

 1/27/04


U.S. Patent 6,528,384 to Beckmann et al., "Method for Manufacturing a Trench Capacitor," describes a method for manufacturing a trench capacitor.

U.S. Patent 6,495,874 to Kawamura et al., "Semiconductor Device and Production Process Thereof," describes a semiconductor device and production process thereof.

U.S. Patent 6,384,442 to Chen, "Fabrication Process for Metal-Insulator-Metal Capacitor with Low Gate Resistance," describes a fabrication process for metal-insulator-metal capacitor with low gate resistance.

U.S. Patent 6,346,454 to Sung et al., "Method of Making Dual Damascene Interconnect Structure and Metal Electrode Capacitor," describes a method of making dual damascene interconnect structure and metal electrode capacitor.

Sincerely,

  
Stephen B. Ackerman,  
Reg. No. 37761

Form PTO-1449

Doctor Number (Copies)

Application Number

TSMC-02-1193

10/694, 684

Applicant

Ping-Yi Hsin et al.

Filing Date

10/28/03

Group Art Unit

INFORMATION DISCLOSURE CITATION  
IN AN APPLICATION

(Use several sheets if necessary)

## U. S. PATENT DOCUMENTS

[illegible]

## FOREIGN PATENT DOCUMENTS

[illegible]

OTHER DOCUMENTS (Including Author, Title, Date, Portion or Pages, Etc.)

[illegible]

EXAMINER

DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.



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| \_\_\_\_\_ |

ASSOCIATE POWER OF ATTORNEY

I hereby appoint Stephen G. Stanton, registration number 35,690, as my associate attorney in this case. His telephone number is (610) 296-5194.

Please continue to direct all correspondence in this case to the undersigned attorney.

Respectfully submitted,



Stephen B. Ackerman,

Principal attorney of record